

<u>0.13 ||</u>

Abbreviated symbol : K34

# 0.9V Drive Nch + Nch MOSFET

## Structure

Silicon N-channel MOSFET

#### Features

1) High speed switing.

2) Small package(EMT6).

3)Ultra low voltage drive(0.9V drive).

## Application

Switching

## Packaging specifications

	<b>.</b>	
	Package	Taping
Туре	Code	T2R
Basic ordering unit	Basic ordering unit (pieces)	8000
EM6K34		0

## • Absolute maximum ratings $(T_a = 25^{\circ}C)$

#### <It is the same ratings for Tr1 and Tr2.>

Param	eter	Symbol	Limits	Unit
Drain-source voltage		V <sub>DSS</sub>	50	V
Gate-source voltage		V <sub>GSS</sub>	±8	V
Drain current	Continuous	I <sub>D</sub>	±200	mA
Drain current	Pulsed	I <sub>DP</sub> *1	±800	mA
Source current	Continuous	l <sub>s</sub>	125	mA
(Body Diode)	Pulsed	<sup>*1</sup> ا	800	mA
Power dissipation		P <sub>D</sub> *2	150	mW / TOTAL
		۰D	120	mW / ELEMENT
Channel temperature		Tch	150	°C
Range of storage tem	perature	Tstg	-55 to +150	°C

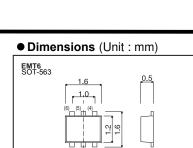
\*1 Pw⊴10μs, Duty cycle⊴1%

\*2 Each terminal mounted on a recommended land.

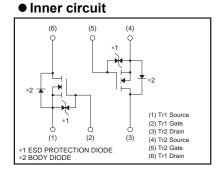
#### Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to Ambient	Rth (ch-a)*	833	°C/W/TOTAL
	nun (cn-a)	1042	°C/W/ELEMENT

\* Each terminal mounted on a recommended land.



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## Data Sheet

## • Electrical characteristics ( $T_a = 25^{\circ}C$ )

< It is the same ratings for Tr1 and Tr2.>

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Gate-source leakage	I <sub>GSS</sub>	-	-	±10	μA	$V_{GS}=\pm 8V, V_{DS}=0V$
Drain-source breakdown voltage	V (BR)DSS	50	-	-	V	I <sub>D</sub> =1mA, V <sub>GS</sub> =0V
Zero gate voltage drain current	I <sub>DSS</sub>	-	-	1	μA	$V_{DS}$ =50V, $V_{GS}$ =0V
Gate threshold voltage	V <sub>GS (th)</sub>	0.3	-	0.8	V	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA
		-	1.6	2.2		I <sub>D</sub> =200mA, V <sub>GS</sub> =4.5V
		-	1.7	2.4		I <sub>D</sub> =200mA, V <sub>GS</sub> =2.5V
Static drain-source on-state resistance	R <sub>DS (on)</sub> *	-	2.0	2.8	Ω	I <sub>D</sub> =200mA, V <sub>GS</sub> =1.5V
resistance		-	2.2	3.3		I <sub>D</sub> =100mA, V <sub>GS</sub> =1.2V
		-	3.0 9.0 I <sub>D</sub> =10mA, V <sub>GS</sub> =0.9	I <sub>D</sub> =10mA, V <sub>GS</sub> =0.9V		
Forward transfer admittance	۱Y <sub>fs</sub> ۱*	0.2	-	-	S	$I_D=200mA, V_{DS}=10V$
Input capacitance	C <sub>iss</sub>	-	26	-	pF	V <sub>DS</sub> =10V
Output capacitance	C <sub>oss</sub>	-	6	-	pF	V <sub>GS</sub> =0V
Reverse transfer capacitance	C <sub>rss</sub>	-	3	-	pF	f=1MHz
Turn-on delay time	t <sub>d(on)</sub> *	-	5	-	ns	I <sub>D</sub> =100mA, V <sub>DD</sub> ≒25V
Rise time	t <sub>r</sub> *	-	8	-	ns	V <sub>GS</sub> =4.5V
Turn-off delay time	t <sub>d(off)</sub> *	-	17	-	ns	R <sub>L</sub> =250Ω
Fall time	t <sub>f</sub> *	-	43	-	ns	$R_{G}=10\Omega$

\*Pulsed

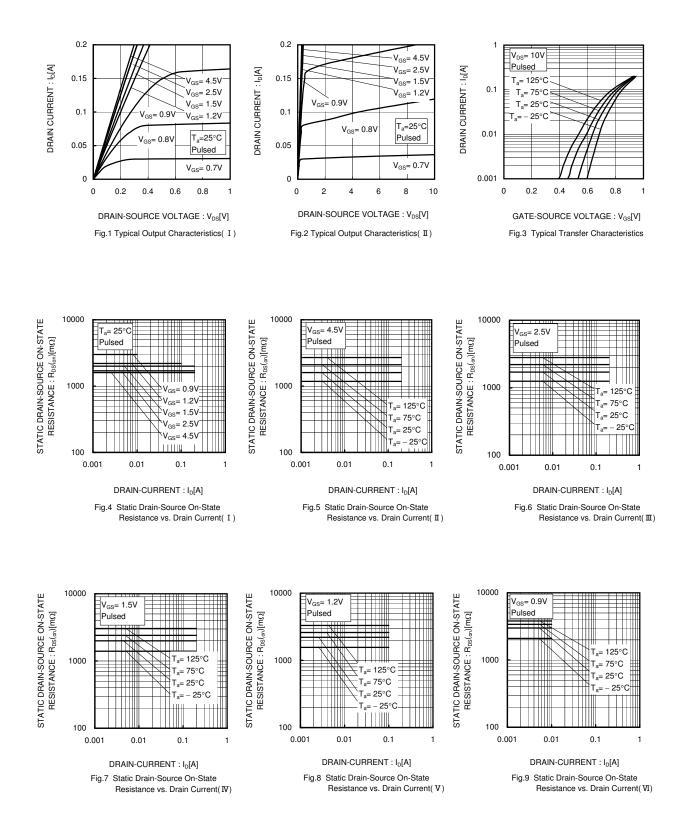
## ●Body diode characteristics (Source-Drain) (T<sub>a</sub> = 25°C)

<It is the same ratings for Tr1 and Tr2.>

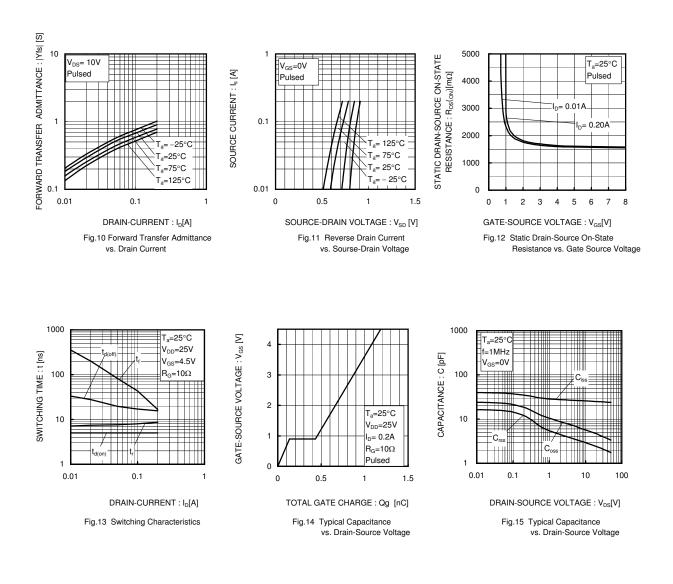
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward Voltage	$V_{SD}^{*}$	-	-	1.2	V	$I_s$ =200mA, $V_{GS}$ =0V

\*Pulsed

#### • Electrical characteristics curves



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## Measurement circuits

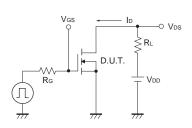


Fig.1-1 Switching time measurement circuit

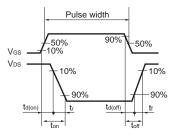


Fig.1-2 Switching waveforms

## Notice

This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.

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